Diode Semiconductor Device - Page 1 of 1



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	sure Material:
Metal	
	II Length:
	inches
	II Diameter:
	en 1.031 inches and 1.063 inches
Moun	ting Facility Quantity:
1	
Joint	Electronic Device Engineering Council/jedec/case Outline Designation:
Do-30	
Moun	ting Method:
Threa	ded stud
Featu	res Provided:
Herme	etically sealed case
	II Width Across Flats:
1.227	inches
Threa	d Size:
0.500	inches
Semio	conductor Material:
Silicor	1
Voltag	ge Rating In Volts Per Characteristic:
200.0	reverse voltage, peak
Curre	nt Rating Per Characteristic:
150.00	Damperes average forward current averaged over a full 60-hz cycle
Maxin	num Operating Tempurature Per Measurement Point:
200.0	degrees celsius case
Threa	d Series Designator:
Unf	
Termi	nal Type And Quantity:
1 threa	aded stud and 1 uninsulated wire lead w/terminal lug
Speci	fication Data:
80131	-release2820 professional/industrial association specification
Shelf	Life:
N/a	
Unit C	Of Measure:
Demil	itarization:
No	
Fiig:	
	0